

General Description

The MAX4675/MAX4676 single analog switches feature 3Ω (max) on-resistance (R_{ON}) and 0.7Ω flatness when operating from dual ±5V supplies. These switches can handle Rail-to-Rail® analog signals. Off-leakage current is 0.1nA at $T_A = +25$ °C. The MAX4675/MAX4676 are ideal in low-distortion applications and are the preferred solution over mechanical relays in automated test equipment or applications where current switching is required. They are more reliable than mechanical relays, have low power requirements (<1µA), and are available in a space-saving 6-pin SOT23 package.

The MAX4675 has a single normally open (NO) switch, and the MAX4676 has a single normally closed (NC) switch.

The MAX4675/MAX4676 operate from either a single +2.7V to +5.5V or dual ±2.7V to ±5.5V supplies, making them ideal for use in digital card applications and single-ended 75 Ω systems.

Applications

Reed Relay Replacement

Test Equipment

Communications Systems

PBX, PABX Systems

Audio Signal Routing

Avionics

ADC Systems

Data-Acquisition Systems

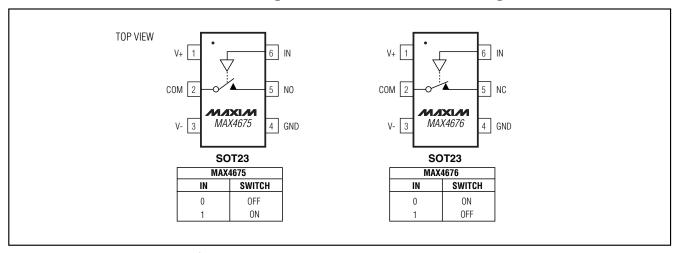
Features

- ♦ 3Ω (max) Ron
- ♦ 0.7Ω (max) Ron Flatness
- ◆ Dual ±2.7V to ±5.5V or Single +2.7V to +5.5V **Supply Range**
- ♦ Off-Isolation
 - -75dB at 1MHz, Dual Supply -65dB at 1MHz, Single Supply
- ◆ -3dB Bandwidth 250MHz
- ♦ Rail-to-Rail Signal Handling

Ordering Information

PART	TEMP. RANGE	PIN- PACKAGE	SOT MARK	
MAX4675EUT-T	-40°C to +85°C	6 SOT23-6	AAND	
MAX4676EUT-T	-40°C to +85°C	6 SOT23-6	AANE	

Pin Configurations/Functional Diagrams/Truth Tables



Rail-to-Rail is a registered trademark of Nippon Motorola, Ltd.

MIXIM

Maxim Integrated Products 1

For free samples and the latest literature, visit www.maxim-ic.com or phone 1-800-998-8800. For small orders, phone 1-800-835-8769.

ABSOLUTE MAXIMUM RATINGS

V+ to GND	0.3V to +6V	Continuous Power Dissipation (T _A = +70	л°С)
V- to GND	+0.3V to -6V	6-Pin SOT23 (derate 8.7mW/°C above	+70°C)691mW
V+ to V	12V	Operating Temperature Range	40°C to +85°C
IN to GND	0.3V to (V+ + 0.3V)	Junction Temperature	+150°C
All Other Pins (Note 1)	(V - 0.3V) to $(V + 0.3V)$	Storage Temperature Range	
Continuous Current (NO, NC, COM)	±100mA	Lead Temperature (soldering, 10s)	+300°C
Peak Current (NO, NC, COM, pulsed a			
(10% duty cycle)			

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

Note 1: Signals on NO, NC, COM, or IN exceeding V+ or V- will be clamped by internal diodes. Limit forward diode current to maximum current rating.

ELECTRICAL CHARACTERISTICS—DUAL SUPPLIES

 $(V+ = +5V \pm 10\%, V- = -5V \pm 10\%, GND = 0, V_{IH} = +2.4V, V_{IL} = 0.8V, T_A = T_{MIN} \text{ to } T_{MAX}, \text{ unless otherwise noted.}$ Typical values are at $T_A = +25^{\circ}C$.) (Notes 2, 3)

PARAMETER	SYMBOL	CONDITIONS		MIN	TYP	MAX	UNITS	
ANALOG SWITCH								
Input Voltage Range	V _{COM} , V _{NO} , V _{NC}			V-		V+	V	
On Decistores	Davi	V+ = 4.5V, V- = -4.5V, ICOM	T _A = +25°C		2.4	3	0	
On-Resistance	Ron	= 50mA; V_{NO} or V_{NC} = $\pm 3.3 V$	TA = TMIN to TMAX			4	Ω	
On-Resistance Flatness	D.	V+ = 4.5V, V- = -4.5V,	T _A = +25°C		0.4	0.7		
(Note 4)	RFLAT	$I_{COM} = 50$ mA; V_{NO} or $V_{NC} = \pm 3.3$ V, 0	$T_A = T_{MIN}$ to T_{MAX}			1.0	Ω	
NC or NO Off-Leakage	1	V+ = 5.5V, V- = -5.5V,	T _A = +25°C	-1	0.1	1	A	
Current	IN_(OFF)	V _{COM} = 4.5V; V _{NO} or V _{NC} = ±4.5V	$T_A = T_{MIN}$ to T_{MAX}	-10		10	nA	
COM Off Lealing Current	1	F) $V_{COM} = +4.5V$; V_{NO} or	T _A = +25°C	-1	0.1	1	nA	
COM Off-Leakage Current	ICOM(OFF)		$T_A = T_{MIN}$ to T_{MAX}	-10		10		
COM On Landson Comment	ICOM(ON)	$V+ = 5.5V, V- = -5.5V, V_{COM} = \pm 4.5V; V_{NO} \text{ or } V_{NC} = \pm 4.5V \text{ or floating}$ $T_{A} = +25^{\circ}C$ $T_{A} = T_{MIN} \text{ to } T_{MAX}$	T _A = +25°C	-2	0.1	2	n A	
COM On-Leakage Current	ICOM(ON)		$T_A = T_{MIN}$ to T_{MAX}	-20		20] IIA	
LOGIC INPUT								
Input Low Voltage	V _{IL}					0.8	V	
Input High Voltage	VIH			2.4			V	
Input Leakage Current	I _{IN}			-1	0.005	1	μΑ	
DYNAMIC	DYNAMIC							
T 0 T		V+ = +4.5V, V- = -4.5V;	T _A = +25°C		135	300		
Turn-On Time	ton	V_{NO} or $V_{NC} = 3.3V$, $R_L = 300\Omega$, $C_L = 35pF$, Figure 2	$T_A = T_{MIN}$ to T_{MAX}			375	ns	
Turn Off Time	+0==	V+ = +4.5V, V- = -4.5V;	T _A = +25°C		50	110	200	
Turn-Off Time	toff	V_{NO} or $V_{NC} = 3.3V$, $R_L = 300\Omega$, $C_L = 35pF$, Figure 2	$T_A = T_{MIN}$ to T_{MAX}			125	ns	

2 ______ /N/XI/M

ELECTRICAL CHARACTERISTICS—DUAL SUPPLIES (continued)

 $(V+ = +5V \pm 10\%, V- = -5V \pm 10\%, GND = 0, V_{IH} = +2.4V, V_{IL} = 0.8V, T_A = T_{MIN} \text{ to } T_{MAX}, \text{ unless otherwise noted.}$ Typical values are at $T_A = +25^{\circ}C$.) (Notes 2, 3)

PARAMETER	SYMBOL	CONDITIO	NS	MIN	TYP	MAX	UNITS
Charge Injection	Q	$R_{GEN} = 0\Omega$, $C_L = 1nF$, $V_{GEN} = 0$, Figure 3	T _A = +25°C		87		рС
Off-Isolation	V _{ISO}	$R_L = 50\Omega$, $C_L = 5pF$, $f = 1MHz$, Figure 4	T _A = +25°C		-75		dB
On-Channel Bandwidth (-3dB)	BW	$R_S = 50\Omega$, $R_L = 50\Omega$			250		MHz
NC or NO Off-Capacitance	C _(N_OFF)	f = 1MHz, Figure 5	T _A = +25°C		85		pF
COM Off-Capacitance	C(COMOFF)	f = 1MHz, Figure 5	T _A = +25°C		85		рF
On-Capacitance	C _(ON)	f = 1MHz, Figure 5	$T_A = +25^{\circ}C$		350		рF
POWER SUPPLY							
Supply Voltage	V+, V-			±2.7		±5.5	V
Positive Supply Current	l+	V _{IN} = 0 or 5.5V, V+ =	T _A = +25°C		0.002	1	^
		5.5V, V- = -5.5V	$T_A = T_{MIN}$ to T_{MAX}		•	10	μΑ
Negative Supply Current	l-	V _{IN} = 0 or 5.5V, V+ = 5.5V, V- = -5.5V	$T_A = +25^{\circ}C$ $T_A = T_{MIN} \text{ to } T_{MAX}$	-1 -10	-0.002		μА

ELECTRICAL CHARACTERISTICS—SINGLE SUPPLY

(V+ = +5V \pm 10%, V- = 0, GND = 0, V_{IH} = +2.4V, V_{IL} = 0.8V, T_A = T_{MIN} to T_{MAX}, unless otherwise noted. Typical values are at T_A = +25°C.) (Notes 2, 3)

PARAMETER	SYMBOL	CONDITIONS		MIN	TYP	MAX	UNITS
ANALOG SWITCH							
Input Voltage Range	V _{COM} , V _{NO} , V _{NC}					V+	V
On Desistance	D	V+ = 4.5V; I _{COM} = 50mA;	T _A = +25°C		3.5	5.75	Ω
On-Resistance	R _{ON}	V_{NO} or $V_{NC} = 3.3V$	$T_A = T_{MIN}$ to T_{MAX}			7.5	
On-Resistance Flatness	Dr. AT	V+ = 4.5V; I _{COM} = 50mA; V _{NO} or V _{NC} = 1.5V, 2.5V, 3.3V T _A = +25°C T _A = T _{MIN} to T _{MA}	T _A = +25°C		0.4	1.6	Ω
(Note 4)	R _{FLAT}		$T_A = T_{MIN}$ to T_{MAX}			2	22
NC or NO Off-Leakage	lu (oss)	$V+ = 5.5V$; V_{NO} or $V_{NC} = 4.5V$ or 0;	T _A = +25°C	-1	0.1	1	20
Current	IN_(OFF)	$V_{COM} = 0 \text{ or } 4.5V$	$T_A = T_{MIN}$ to T_{MAX}	-10		10	nA nA
COM Off Laster to Comment	loon(OFF)	$V+ = 5.5V$; V_{NO} or $V_{NC} = 4.5V$ or 0;	T _A = +25°C	-1	0.1	1	nA
COM Off-Leakage Current	ICOM(OFF)	V _{COM} = 0 or 4.5V	$T_A = T_{MIN}$ to T_{MAX}	-10		10	I IIA



ELECTRICAL CHARACTERISTICS—SINGLE SUPPLY (continued)

 $(V+ = +5V \pm 10\%, V- = 0, GND = 0, V_{IH} = +2.4V, V_{IL} = 0.8V, T_A = T_{MIN}$ to T_{MAX} , unless otherwise noted. Typical values are at $T_A = +25$ °C.) (Notes 2, 3)

PARAMETER	SYMBOL	CONDITIONS		MIN	TYP	MAX	UNITS	
COM On-Leakage Current	loon (on)	V+ = 5.5V; V _{NO} or V _{NC} = 0, 4.5V,	T _A = +25°C	-2	0.2	2	nA	
COM On-Leakage Current	ICOM (ON)	or floating; VCOM = 0 or 4.5V	$T_A = T_{MIN}$ to T_{MAX}	-20		20	IIA	
LOGIC INPUT								
Input Low Voltage	V _{IL}					0.8	V	
Input High Voltage	V _{IH}			2.4			V	
Input Leakage Current	I _{IN}			-1	0.005	1	μΑ	
DYNAMIC								
		V+ = +4.5V; V_{NO} or $V_{NC} = +3.3V,$	$T_A = +25^{\circ}C$		350	700		
Turn-On Time	ton	$R_L = 300\Omega$, $C_L = 35pF$, Figure 2	$T_A = T_{MIN}$ to T_{MAX}			850	ns	
		V+ = +4.5V; V _{NO} or V _{NC} =	T _A = +25°C		55	150		
Turn-Off Time	tOFF	$+3.3V$, $R_L = 300\Omega$, $C_L = 35pF$, Figure 2	$T_A = T_{MIN}$ to T_{MAX}			160	ns	
Charge Injection	Q	$R_{GEN} = 0\Omega$, $C_L = 1nF$, $V_{GEN} = 2.5V$, Figure 3	T _A = +25°C		31		рС	
Off-Isolation	V _{ISO}	$R_L = 50\Omega$, $C_L = 5pF$, $f = 1MHz$, Figure 4	T _A = +25°C		-65		dB	
On-Channel Bandwidth (-3dB)		$R_S = 50\Omega$, $R_L = 50\Omega$			150		MHz	
NC or NO Off-Capacitance	C _(N_OFF)	f = 1MHz, Figure 5	T _A = +25°C		85		pF	
COM Off-Capacitance	C(COMOFF)	f = 1MHz, Figure 5	T _A = +25°C		85		pF	
On-Capacitance	C _(ON)	f = 1MHz, Figure 5	T _A = +25°C		350		pF	
POWER SUPPLY								
Supply Voltage	V+			2.7		5.5	V	
Positive Supply Current		$V_{IN} = 0$ or $5V$,	T _A = +25°C		0.002	1	μА	
Tositive Supply Current	IT	$V+ = 5.5V$ $T_A = T_{MIN}$ to T_{MA}				10		

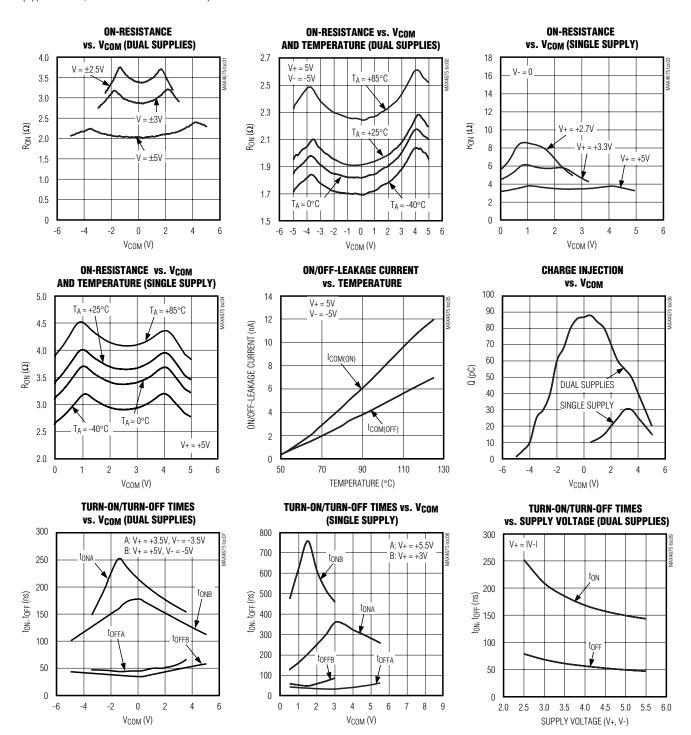
Note 2: Parameters are 100% tested at +25°C only and guaranteed by correlation through the full-rated temperature range.

Note 3: The algebraic convention, where the most negative value is a minimum and the most positive value a maximum, is used in this data sheet.

Note 4: Flatness is defined as the difference between the maximum and minimum value of R_{ON} as measured over the specified analog signal ranges.

Typical Operating Characteristics

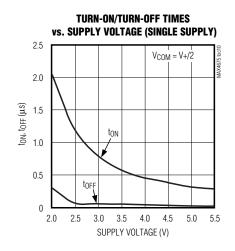
 $(T_A = +25^{\circ}C, \text{ unless otherwise noted.})$

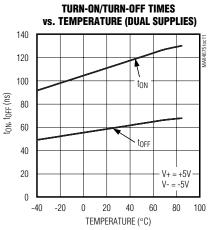


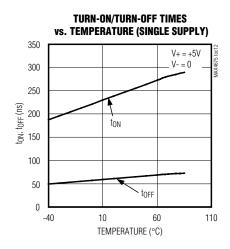
MIXIM

Typical Operating Characteristics (continued)

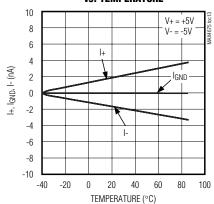
 $(T_A = +25^{\circ}C, \text{ unless otherwise noted.})$



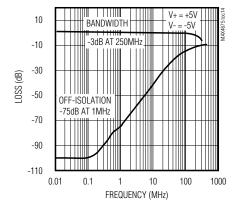




POWER-SUPPLY CURRENT vs. TEMPERATURE



FREQUENCY RESPONSE



Pin Description

	PIN		PIN		FUNCTION
MAX4675	MAX4676	INAME	FONCTION		
1	1	V+	Positive Supply		
2	2	COM	Analog Switch Common Terminals		
3	3	V-	Negative Supply		
4	4	GND	Ground		
5	_	NO	Analog Switch Normally Open Terminal		
_	5	NC	Analog Switch Normally Closed Terminal		
6	6	IN	Logic Input		

6 ______ /N/XI/M

Applications Information

Overvoltage Protection

Proper power-supply sequencing is recommended for all CMOS devices. Do not exceed the absolute maximum ratings because stresses beyond the listed ratings can cause permanent damage to the devices. Always sequence V+ on first, then V-, followed by the logic inputs, NO, NC, or COM. If proper power-supply sequencing is not possible, add two small-signal diodes (D1, D2) in series with the supply pins (Figure 1). Adding diodes reduces the analog signal range to one diode drop below V+ and one diode drop above V- but does not affect the devices' low switch resistance and low leakage characteristics. Device operation is unchanged, and the difference between V+ and V- should not exceed 12V.

Power-supply bypassing improves noise margin and prevents switching noise from propagating from the V+ supply to other components. A 0.1µF capacitor connected from V+ to GND is adequate for most applications.

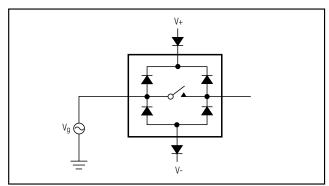


Figure 1. Overvoltage Protection Using External Blocking Diodes

Timing Diagrams/Test Circuits

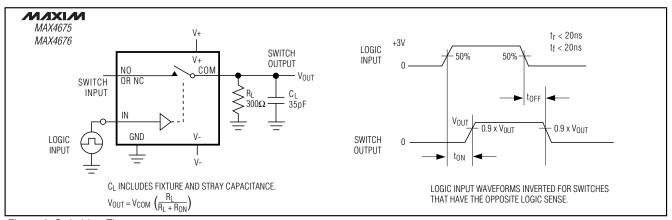


Figure 2. Switching Time

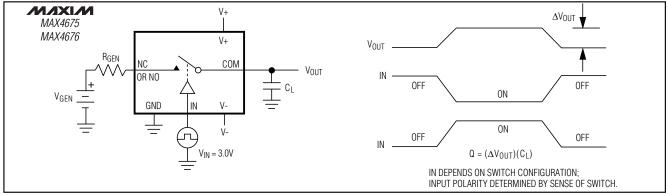


Figure 3. Charge Injection

MIXIM

Timing Diagrams/Test Circuits (continued)

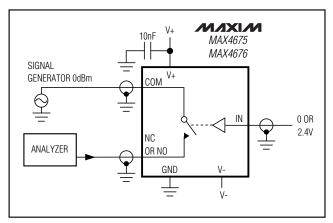


Figure 4. Off-Isolation/On-Channel Bandwidth

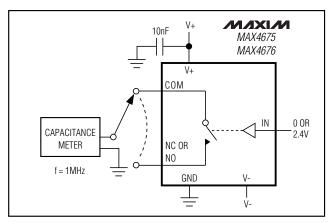
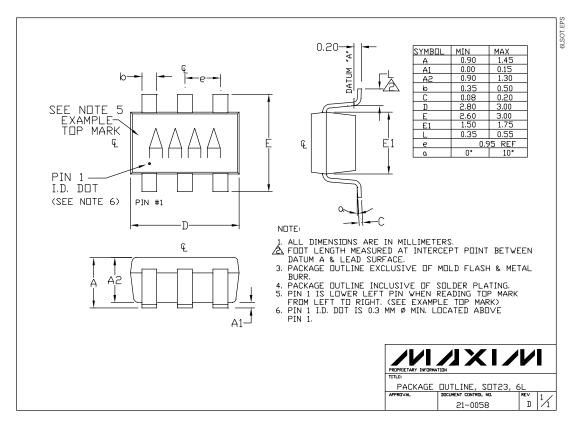


Figure 5. Channel On/Off-Capacitance

Package Information



Maxim cannot assume responsibility for use of any circuitry other than circuitry entirely embodied in a Maxim product. No circuit patent licenses are implied. Maxim reserves the right to change the circuitry and specifications without notice at any time.

8 ______Maxim Integrated Products, 120 San Gabriel Drive, Sunnyvale, CA 94086 408-737-7600

© 2000 Maxim Integrated Products

Printed USA

is a registered trademark of Maxim Integrated Products.